L6287



POWER COMBO DRIVER

DESCRIPTION

The F-VHS Motor Driver COMBO IC includes a double three phase brushless motor driver plus a DC full bridge motor driver for VCR application.

The package is SDIP42 (38+2+2 pin ground frame).

The device is realized in BCD technology with power LDMOS output stages.

The gate drive for high side stages is provided by an internal charge pump with two external capacitors. The first three phase motor driver is devoted to the DRUM motor control.

The phase sequence update signal is provided initially by an external start-up signal (FSTART), whose frequency is internally divided by four, while, during normal operation, is provided by an optical tacho converter signal.

This signal is used as clock and reset for the state machine.

The regulation of the speed is externally provided by means of PWM signal generated by the μ P (DPWM), without external sensing resistor. The feedback to the μ P unit is given by a suitable open drain output signal (PUD) synchronized by the internal state machine.

The second three phase motor driver is devoted to the CAPSTAN control. While the DRUM will always spin in a fixed direction, the CAPSTAN motor needs a more sophisticated logic to control the changes in spin direction.

The motor position detection is carried out by means of three comparators for Hall effect sensors. The loop regulation for this motor is still provided by the μ P with the signals CPWM and CDIR.

The LOADING motor section include a full bridge DC motor driver. The motor operations are directly set by the inputs LPWM, LDIR according to the truth table reported on the page 5.

The device also includes a circuit for early thermal alarm, last thermal alarm and thermal shutdown with hysteresys. The output of this stage is an open drain, kept ON during normal operations.

The THERM signal follows the inverted FSTART signal between early warning and last warning temperature, while remains in high impedance (OFF) after lastwarning temperature and during thermal shutdown.



The STANDBY state of the device is imposed by

- THERMAL SHUTDOWN
- UNDERVOLTAGE ON VCC SUPPLY
- EXTERNAL SIGNAL FSTART;

This state is imposed automatically after a defined time-out.

The time-out is realized by sensing the falling edges of the FSTART signal: if no edges are recorded for a time interval greater than a certain time constant, the STANDBY condition is generated.

The time constant is defined by the external capacitor CTO.

In the STANDBY state the main functions (upper power stages, opto decoder, etc) of the device are turned off in order to minimize the power consumption.

The device also implement a HEATER function. The HEATER transistor is OFF during thermal shutdown, undervoltage condition and during normal working mode.

The HEATER transistor is driven ON when the external STANDBY condition is present according to the following table:

FSTART	HIGH	LOW
HEATER	OFF	ON

During the ON condition, the specified heater Ron is not guaranteed if all the voltage supplies are not at their minimum nominal value.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Drum Supply Voltage	20	V (**)
VDC	Capstan Supply Voltage	20	V (**)
V _{DL}	Loading Supply Voltage	20	V (**)
UPPER POWER Vds max	Motor Output to Ground Voltage	20	V(***)
LOWER POWER V _{DS MAX}	Motor Output to Supply Voltage	20	V (***)
Vcc	Logic Supply Voltage	7	V
Vs	Special Supply Voltage	7	V
lp1	Loading Motor Peak Current ($T_{on} = 1\mu s$ Duty Cycle = 2%)	1.6	А
lpd	Drum Motor Peak Current (Ton = 1µs Duty Cycle = 2%)	1.4	А
Ipc	Capstan Motor Peak Current (Ton = 1µs Duty Cycle = 2%)	1.8	А
Vil	Logic Input Low State Voltage	-0.1	V
Vih	Logic Input High StateVoltage	7	V
Vtherm	Open Drain Maximum Voltage	7	V
Vheat	Open Drain Maximum Voltage	20	V (**)

(**) Not operative - STANDBY condition (***) Each motor driver

PINS CONNECTION

r		1
H2+ 🗖	1 42	ם טסב
н1- 🗖	2 41	☐ H2-
H1+ 🗖	3 40	□ нз+
LPWM 🗖	4 39	🗅 нз-
LDIR 🗖	5 38	□ CPWM
СР2 🗖	б 37	
VCP 🗖	7 35	ם כדס
СР1 🗖	8 35	🗆 σουτυ
νοι 🗖	9 34	ουτν
μουτά 🗖	10 33	Солтя
GNDL 🗖	11 32	
GNDL 🗖	12 31	
μαυτε Π	13 30	ωτυος 🗆
HEATER 🗖	14 29	ντυσα 🗆
Vee 🗖	15 28	υτυος 🗆
vs ⊑	16 27	D DPWM
SGND 🗖	17 25	FSTART
ם מס	18 25	ממע 🗆
דס 🗖	19 24	THERM
oc 🗖	20 23	
OR 🗖	21 22	LGND
L	M931 6287 - 81A	-

THERMAL DATA

Symbol	Parameter	Value	Unit
R _{thj-amb}	Thermal Resistance Junction to Ambient	48	°C/W
R th j-pins	Thermal Resistance Junction to Pin	15	°C/W

Note: Batwing pin.



BLOCK DIAGRAM



PIN DESCRIPTION

VOLTAGE SUPPLIES (The power supply voltage VDD, VDC, VDL must be connected toghether externally)			
Vdd	Power supply voltage for drump motor		
VDC	Power supply voltage for capstan motor		
Vdl	Power supply voltage for loading motor and charge pump		
Vcc	Logic voltage supply		
Lgnd	Logic Ground		
GND R	Capstan + drum power ground		
GND L	Loading + Charge pump Power ground		
Vs	Analog voltage supply		
SGND	Analog ground		
Note: The V _{CC} and	d V _S Power Supply must be together either at maximum or minimum value.		
DRUM MOTOR			
D ουτ υ	Winding Output U		
D ουτ ν	Winding Output V		
D оυт w	Winding Output W		
Dрwм	PWM logic pulse input. Control signal generated by μP for dump motor current regulation.		
Pud	Logic output position feedback generated by the translator logic		
OD	Optocoupler diode output		
OC	External capacitor for tacho-converter integrator		
ОТ	Input for optocoupler transistor		
OR	Tacho-converter external resistor. This resistor defines the full-light current level of the tacho.		
CAPSTAN MOTO	DR		
C ουτ υ	Winding Output U		
C OUT V	Winding Output V		
Соит w	Winding Output W		
Срум	PWM logic pulse input. Control signal generated by μP for current regulation.		
CDIR	Motor Direction Logic Input Signal		
H1+	Hall sensor differential input		
H1-			
H2+	Hall sensor differential input		
H2-			
H3+	Hall sensor differential input		
H3-			
LOADING MOTO	R		
LOUT A	Winding Output A		
LOUT B	Winding Output B		
Lрwм	PWM logic input.		
LDIR	Direction logic input		
SERVICES			
HEATER	Open drain output for heater resistor		
Vср	Charge pump storage capacitor pin		
CP1	Bootstrap Capacitor pin		
CP2	Bootstrap Capacitor pin		
THERM	Open drain thermal alarm output		
FSTART	Start-up logic signal for drum motor		
СТО	Time out capacitor output		



ELECTRICAL CHARACTERISTICS (Tj = 0 to125°C; $V_{CC} = V_S = 5V \pm 5\%$; $V_{DC} = V_{DL} = V_{DD} = 10$ to 18V; unless otherwise specified.)

POWER SUPPLY

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
(#)V _{DD}	Drum Power Supply Voltage		10		18	V
(#)V _{DC}	Capstan Power Supply Voltage		10		18	V
(#)V _{DL}	Loading Power Supply Voltage		10		18	V
Vcc	Logic Power Supply Voltage		4.5		5.5	V
Vs	Sensor Power Supply Voltage		4.75		5.25	V
V _{CCth}	Undervoltage Threshold		3.6		4.4	V

WARNING

The functionality of the I.C. is guaranted in this voltage range. Nevertheless the specified operating voltages (VDC, VDD, VDL), must be selected according to the load characteristics. Proper cautions must be taken in the application in order to assure that the drain-source voltage across each output power transistor does not exceed 20V max.

LOADING MOTOR

ACTIVATION TRUTH TABLE

INPUT		OUTPUT		
LPWM	LDIR	LOUTA	LOUTB	
0	0	LOW	LOW	
0	1	LOW	LOW	
1	0	HIGH	LOW	
1	1	LOW	HIGH	

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
RDSH	High Side R _{DSonH}				2	Ω
R _{DSL}	Low Side RDSonL				2	Ω
(*)I _{OL}	DC Output Current				800	mA
(*)I _{pl}	Peak Output Current	DUTY CYCLE = 10%; ton = 500ms			1	A

DRUM MOTOR

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I _{cd}	DC Output Current				400	mA
(*)I _{cdp}	Peak Output Current				600	mA
(*)I _{pdb}	Peak Output Current	DUTY CYCLE = 10%; ton = 500ms			800	mA
R _{DSH}	High Side RDSonH				1.6	Ω
R _{DSL}	Low Side RDSonL				1.6	Ω

CAPSTAN MOTOR

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I _{co}	DC Output Current				800	mA
(*)I _{cop}	Peak Output Current				1	А
(*)I _{pob}	Peak Output Current	DUTY CYCLE = 10%; ton = 1ms			1.5	A
R _{DSH}	High Side RDSonH				1	Ω
R _{DSL}	Low Side RDSonL				1	Ω

(*) WARNING These current values are compatible with the structure of the IC power structure. Nevertheless the use of these current levels could produce junction temperatures that force IC outside of the operative range due to the thermal characteristics of the choosen package.



ELECTRICAL CHARACTERISTICS (continued) DRUM TACHO CONVERTER

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
l _{od}	Open Loop Output Current	$V_{od} = 1V; I_{oc} = 100\mu A$ (Note 1)	30		60	mA
l _{ot}	Full Light Current Range		0.5		3	mA
l _{oc}	Sink Current	$V_{or} = 0; I_{od} = 0$	0.2		0.5	μΑ
l _{ot} vs l _{or}	Mismatch			5	10	%
V _{ref}	Opto Resistor Reference	Vs = 4.75V	3.36		3.72	V
	Voltage	$V_S = 5V$	3.54		3.91	V
		Vs = 5.25V	3.72		4.11	V
V _{oc}	Open Loop Opto Capacitor Voltage	$V_{OD} = 1V$ see Fig. 1 $V_{S} = 4.75V$ $V_{S} = 5V$ $V_{S} = 5.25V$	2.75			V
V _{thr1}	Clock Threshold Voltage	Vs = 4.75V	2.19		2.42	V
		$V_S = 5V$	2.30		2.54	V
		Vs = 5.25V	2.42		2.67	V
V _{thr2}	Reset Threshold Voltage	Vs = 4.75V	0.30		0.33	V
		Vs = 5V	0.32		0.35	V
		Vs = 5.25V	0.33		0.37	V
t _{pud}	μP Syncro Pulse Duration		1		3	μs
I _{pud1}	Open Drain Sink Current	Vo = 0.4V	5			mA

Note 1: The suggested C_{opt} external capacitor value is 5µF (±5%)

HALL COMPARATOR

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vin	Input Voltage Range		0.5		2.7	V
l _b	Input Bias Current				1	μA
V _{of}	Input Offset Voltage				8	mV
V _{hy}	Switchable Hysteresys	Vref = 1.5V;	10		40	mV

THERMAL PROTECTION

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I _{therm}	Open Drain Sink Current	Vout = 0.4V (see note 1)	5			mA
Ts	Shutdown Temperature		155	170	185	°C
T _{sdh}	Shutdown Hysteresis			60		°C
T _{al1}	Early Warning Temperature			Ts -40		°C
T _{al2}	Last Warning Temperature	(see note 2)		Ts -20		°C

NOTE 1: Therm output stage is on in the normal temperature range

NOTE 2: In the Tal-TII temperature range therm signal follows the inverted Fstart signal. After TII temperature this output is always in high impedance. If thermal shutdown is reached this pin will remain in this state until the shutdown hysteresys will be recovered.

HEATER

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
R _{dsheat}	Heater R _{DSon}				3	ohm
V _{heat}	Heater Voltage				18	V



ELECTRICAL CHARACTERISTICS (continued.)

LOGIC LEVELS FOR DIGITAL INPUTS (CPWM, CDIR, DPWM, FSTART, LPWM, LDIR)

A pull up resistor Ri is connected between the $C_{\text{DIR}},\,F_{\text{START}},\,L_{\text{PWM}},\,L_{\text{DIR}}$ inputs pads; C_{PWM} and D_{PWM} are left unconnected.

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vil	Input Low Voltage				0.8	V
Vih	Input High Voltage		2			V
Ri	Pull Up Resistor		3.5		10.5	Kohm

TIME OUT STAGE

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I _{cto}	Time Out Output Current	(Note 1)	5		20	uA

Note 1: The suggested external capacitor value is $C_{to} = 1\mu F$ (±20% max) for f_{START} = 20KHz.

Figure 1: Optocircuit Open Loop OC Voltage.





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SDIP42 PACKAGE MECHANICAL DATA

МІД	mm			inch			
Diw.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			5.08			0.20	
A1	0.51			0.020			
A2	3.05	3.81	4.57	0.120	0.150	0.180	
В	0.38	0.46	0.56	0.0149	0.0181	0.0220	
B1	0.89	1.02	1.14	0.035	0.040	0.045	
с	0.23	0.25	0.38	0.0090	0.0098	0.0150	
D	36.58	36.83	37.08	1.440	1.450	1.460	
E	15.24		16.00	0.60		0.629	
E1	12.70	13.72	14.48	0.50	0.540	0.570	
е		1.778			0.070		
e1		15.24			0.60		
e2			18.54			0.730	
e3			1.52			0.060	
L	2.54	3.30	3.56	0.10	0.130	0.140	



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